

Applications

- Base Station Receivers
- Tower Mount Amplifiers
- Repeaters
- FDD-LTE, TDD-LTE, WCDMA
- General Purpose Wireless

Product Features

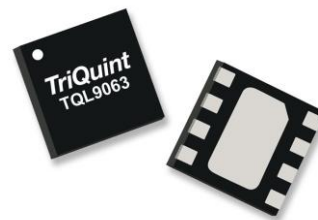
- 0.7 – 4.0 GHz Operational bandwidth
- LNA with integrated bypass mode
- Ability to turn LNA and bypass mode OFF
- Ultra low noise, 0.7 dB at 1.95 GHz
- 19 dB Gain at 1.95 GHz
- +36.3 dBm Output IP3 in LNA Mode
- +39 dBm Input IP3 in Bypass Mode
- Internally matched
- Positive supply only, +3.3 to +5 V
- 2x2 mm 8-pin DFN plastic package

General Description

The TQL9063 is a high-linearity, ultra-low noise gain block amplifier with a bypass mode functionality integrated in the product. At 1.95 GHz, the amplifier typically provides 19 dB gain, +36.3 dBm OIP3, and 0.7 dB noise figure while drawing 77 mA current from a +5 V supply. The component also provides high linearity in the bypass mode with +39 dBm IIP3.

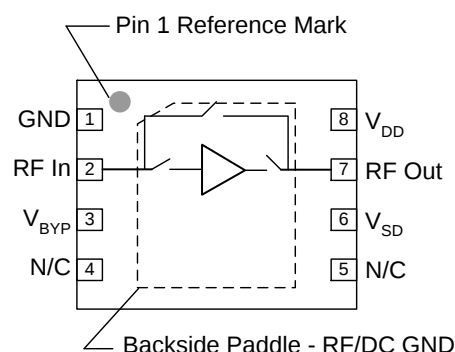
The TQL9063 is internally matched using a high performance E-pHEMT process and only requires four external components for operation from a single positive supply: an external RF choke and blocking/bypass capacitors. This low noise amplifier contains an internal active bias to maintain high performance over temperature.

The TQL9063 covers the 0.7–4.0 GHz frequency band and is targeted for wireless infrastructure. The TQL9063 is packaged in a 2 x 2 mm DFN.



8-pin 2 x 2 mm DFN Package

Functional Block Diagram



Pin Configuration

Pin No.	Label
1	GND
2	RFin
3	V _{BYP}
4, 5	N/C
6	V _{SD}
7	RFout
8	V _{DD}
Backside Paddle	RF/DC GND

Ordering Information

Part No.	Description
TQL9063	700–4000 MHz Bypass LNA
TQL9063-PCB	700–4000 MHz Evaluation Board

Standard T/R size = 2500 pieces on a 7" reel

Absolute Maximum Ratings

Parameter	Rating
Storage Temperature	-65 to 150 °C
Drain Voltage (V _{DD})	+7 V
Input Power (CW)	+22 dBm

Operation of this device outside the parameter ranges given above may cause permanent damage.

Recommended Operating Conditions

Parameter	Min	Typ	Max	Units
Drain Voltage (V _{DD})	+3.3	+5.0	+5.25	V
Operating Temp. Range	-40		+85	°C
T _{ch} (for >10 ⁶ hrs MTTF)			+190	°C

Electrical specifications are measured at specified test conditions. Specifications are not guaranteed over all recommended operating conditions.

Electrical Specifications

Test conditions unless otherwise noted: V_{DD} = +5 V, Temp.=+25°C.

Parameter	Conditions	Min	Typ	Max	Units
Operational Frequency Range		700		4000	MHz
Test Frequency			1950		MHz
Gain	LNA ON, Bypass OFF		19		dB
Input Return Loss	LNA ON, Bypass OFF		12		dB
Output Return Loss	LNA ON, Bypass OFF		9.5		dB
Noise Figure	LNA ON, Bypass OFF		0.7		dB
Output P1dB	LNA ON, Bypass OFF		+21.2		dBm
Output IP3	LNA ON, Bypass OFF, P _{out} =+0 dBm/tone, Δf=1 MHz		+36.3		dBm
Insertion Loss	LNA OFF, Bypass ON		1.4		dB
Return Loss	LNA OFF, Bypass ON		18		dB
Input IP3	LNA OFF, Bypass ON Pin=+3 dBm/tone, Δf=1 MHz		+39		dBm
Isolation	LNA OFF, Bypass OFF		17		dB
Control Voltage, V ₁ , V ₂ ⁽¹⁾	V _{IH}	1.6		V _{DD}	V
	V _{IL}	0		0.5	V
Current, I _D	Bypass OFF		77		mA
	Bypass ON		3		mA
Switching Speed ⁽²⁾	Bypass to LNA Mode		983		ns
	LNA to Bypass Mode		1.9		μs
	LNA to OFF		200		ns
Thermal Resistance, θ _{Jc}	Channel to case		44		°C/W

Notes:

1. These voltages are reference at the turrets labelled V1 and V2 on the circuit schematic on page 3.
2. To achieve these fast switching speeds it is required to place a 91K shunt resistor at the RFout pin 7. Refer pg. 6.

Control Truth Table

V _{BYP}	V _{SD}	State
0	0	LNA ON, Bypass OFF
0	1	LNA OFF, Bypass OFF
1	x	LNA OFF, Bypass ON

De-embedded S-Parameters (LNA Mode)

Test Conditions: $V_{DD}=+5$ V, $I_{DD}=75$ mA (typ.), $T=+25^{\circ}\text{C}$, unmatched 50 ohm system, calibrated to device leads

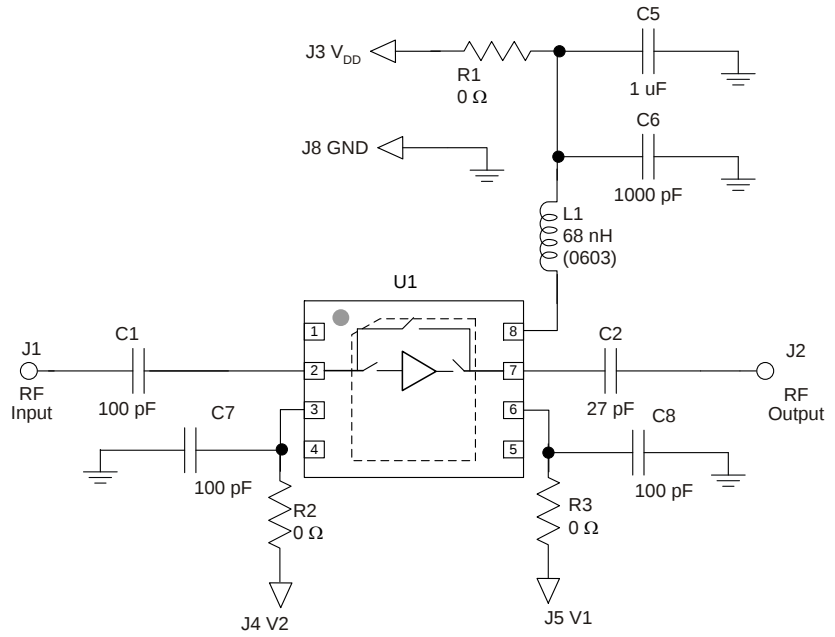
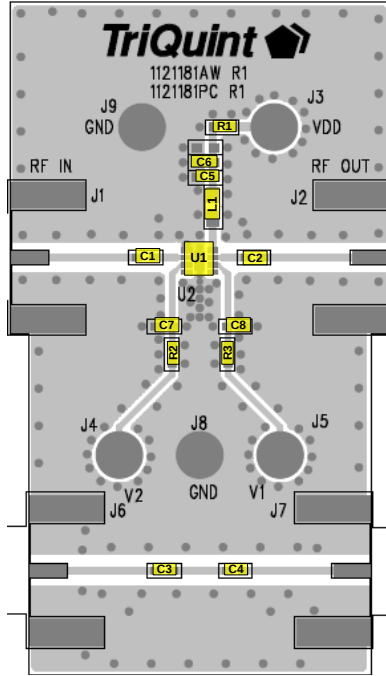
Freq (GHz)	S11 (dB)	S11 (ang)	S21 (dB)	S21 (ang)	S12 (dB)	S12 (ang)	S22 (dB)	S22 (ang)
0.1	-0.34	-18.46	10.47	-40.24	-49.61	153.06	-0.20	-49.20
0.3	-2.46	-56.16	25.14	-126.62	-33.50	92.83	-4.56	-154.92
0.4	-4.03	-65.89	26.03	-156.47	-31.84	74.30	-8.52	162.29
0.6	-5.84	-77.87	25.55	166.99	-30.62	57.06	-14.43	89.93
0.7	-6.38	-83.02	25.03	154.63	-30.24	52.96	-15.50	58.24
0.8	-6.80	-87.84	24.47	144.39	-29.91	50.25	-15.55	32.10
1	-7.45	-96.37	23.34	127.97	-29.31	47.05	-14.41	-4.20
1.2	-7.92	-103.39	22.23	114.95	-28.74	45.37	-13.04	-27.33
1.3	-8.11	-106.38	21.70	109.30	-28.47	44.80	-12.41	-36.16
1.4	-8.27	-109.05	21.18	104.07	-28.20	44.35	-11.83	-43.80
1.5	-8.41	-111.43	20.67	99.21	-27.93	43.96	-11.30	-50.53
1.6	-8.52	-113.55	20.18	94.65	-27.67	43.62	-10.81	-56.56
1.7	-8.62	-115.44	19.69	90.36	-27.42	43.31	-10.36	-62.02
1.8	-8.71	-117.11	19.23	86.30	-27.17	43.01	-9.95	-67.01
1.9	-8.78	-118.58	18.77	82.44	-26.92	42.72	-9.57	-71.62
2	-8.83	-119.88	18.33	78.75	-26.68	42.42	-9.22	-75.91
2.1	-8.88	-121.03	17.90	75.22	-26.45	42.13	-8.90	-79.92
2.2	-8.91	-122.03	17.48	71.83	-26.22	41.83	-8.60	-83.70
2.3	-8.93	-122.92	17.07	68.57	-26.00	41.51	-8.33	-87.26
2.4	-8.94	-123.69	16.66	65.42	-25.78	41.19	-8.08	-90.64
2.5	-8.94	-124.36	16.27	62.37	-25.56	40.86	-7.85	-93.86
2.6	-8.92	-124.95	15.89	59.42	-25.35	40.52	-7.64	-96.93
2.7	-8.91	-125.47	15.52	56.55	-25.15	40.17	-7.45	-99.87
2.8	-8.88	-125.92	15.15	53.76	-24.95	39.81	-7.27	-102.69
3	-8.80	-126.67	14.45	48.39	-24.56	39.06	-6.97	-108.03
3.2	-8.69	-127.26	13.77	43.26	-24.18	38.26	-6.73	-113.00
3.4	-8.56	-127.74	13.12	38.32	-23.82	37.41	-6.53	-117.68
3.6	-8.41	-128.16	12.50	33.56	-23.46	36.52	-6.39	-122.10
3.8	-8.24	-128.54	11.90	28.94	-23.12	35.57	-6.30	-126.30
4	-8.05	-128.93	11.32	24.43	-22.78	34.56	-6.26	-130.29

Noise Parameters (LNA Mode)

Test conditions unless otherwise noted: $V_{DD}=+5$ V, $I_{DD}=75$ mA (typ.), $T=+25^{\circ}\text{C}$, 50 Ohm system

Freq (GHz)	NF _{min} (dB)	GammaOpt (mag)	GammaOpt (deg)	Rn (Ω)
1.5	0.46	0.27	73.07	3.17
1.6	0.47	0.27	76.39	3.15
1.7	0.47	0.28	79.57	3.14
1.8	0.48	0.28	82.63	3.12
1.9	0.49	0.29	85.57	3.11
2	0.50	0.29	88.39	3.10
2.1	0.50	0.30	91.10	3.08
2.2	0.51	0.31	93.70	3.07
2.3	0.52	0.31	96.20	3.06
2.4	0.53	0.32	98.60	3.04
2.5	0.54	0.33	100.91	3.03
2.6	0.55	0.33	103.13	3.02
2.7	0.56	0.34	105.27	3.00

TQL9063-PCB Evaluation Board



See Evaluation Board PCB Information section for PCB material and stack-up.

Bill of Material – TQL9063-PCB

Reference Des.	Value	Description	Manuf.	Part Number
U1	n/a	Bypass LNA	Qorvo	TQL9063
C2	27 pF	CAP, chip, 0402	Various	
C1, C3, C4, C7, C8	100 pF	CAP, 0402, +/-5%, 50V	Panasonic	ECJ-0EC1H101J
C6	1000 pF	CAP, 0402	various	
C5	1.0 uF	Cap., Chip, 0402, 10%, 10V, X5R	various	
R1, R2, R3	0 Ω	RES, 0402, +/-5%, 1/10W	various	
L1	68 nH	IND, 0603, +/-5%	Coilcraft	0603CS-68NXJL

Typical Performance (LNA Mode)

Test conditions unless otherwise noted: $V_{DD} = +5\text{ V}$, $V_1 = 0.5\text{ V}$, $V_2 = 0.5\text{ V}$, $I_D = 77\text{ mA}$, Temp. = +25 °C.

Parameter	Typical Value				Units
Frequency	700	1950	2600	3500	MHz
Gain	+24.3	19.2	17.3	14	dB
Noise Figure	0.64	0.7	0.8	1.1	dB
Input Return Loss	7.8	12	15.3	13.7	dB
Output Return Loss	9.4	9.3	9.5	6	dB
OIP3 (Pout/tone=+0 dBm, $\Delta f = 1\text{ MHz}$)	+35.5	+36.3	+36.1	+36.4	dBm
P1dB	+21.7	+21.2	+21.6	+19.8	dBm

Typical Performance (Bypass Mode)

Test conditions unless otherwise noted: $V_{DD} = +5\text{ V}$, $V_1 = 0.5\text{ V}$ or 1.6 V , $V_2 = 1.6\text{ V}$, $I_D = 3\text{ mA}$, Temp. = +25 °C.

Parameter	Typical Value				Units
Frequency	700	1950	2600	3500	MHz
Insertion Loss	1.2	1.4	1.5	1.6	dB
Input Return Loss	13.6	20	25	20	dB
Output Return Loss	13.6	18	18	17	dB
Input IP3 (Pin/tone=+3 dBm, $\Delta f = 1\text{ MHz}$)	+38.2	+39	+39	+36.6	dBm

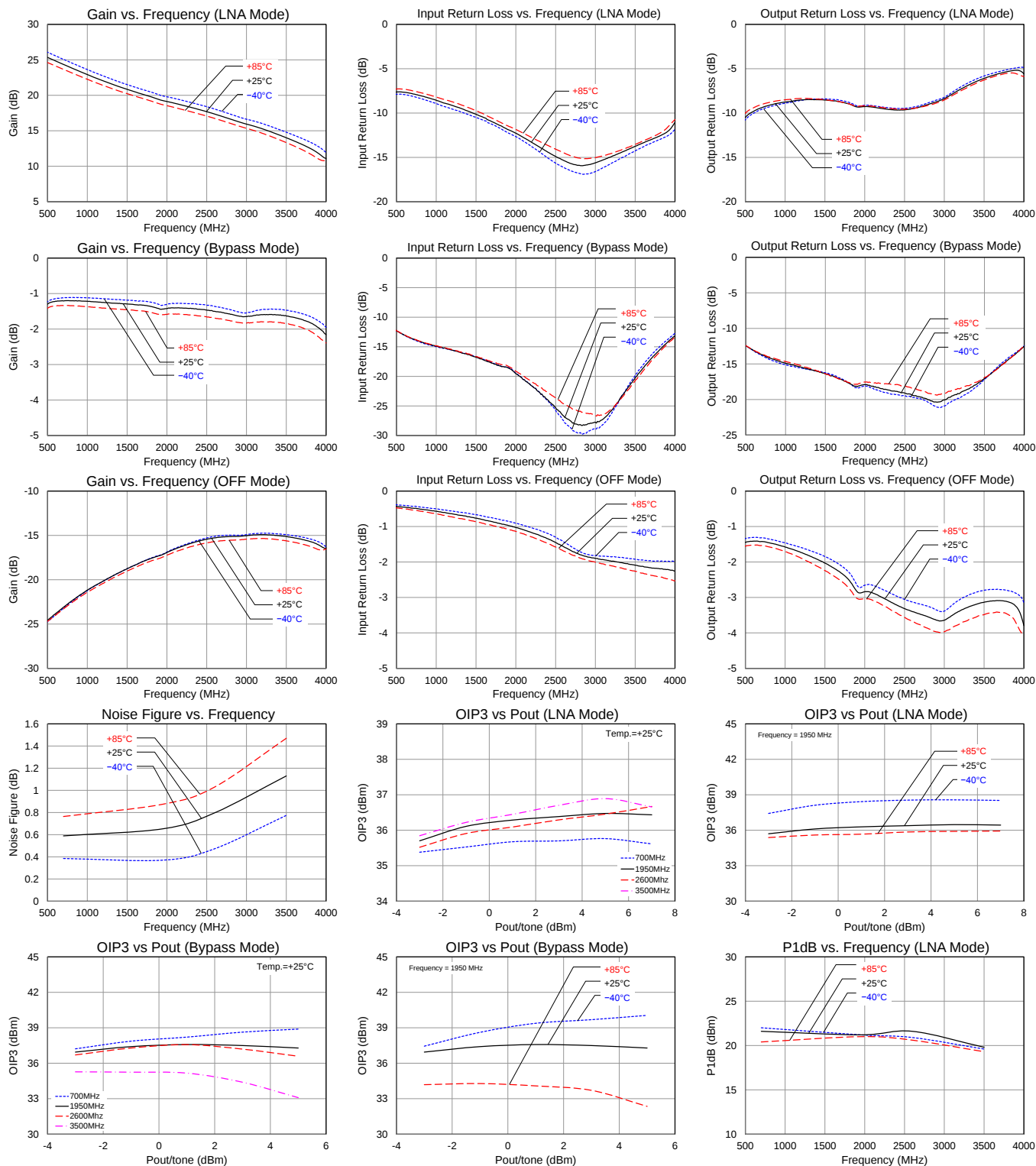
Typical Performance (LNA OFF, Bypass OFF Mode)

Test conditions unless otherwise noted: $V_{DD} = +5\text{ V}$, $V_1 = 1.6\text{ V}$, $V_2 = 0.5\text{ V}$, Temp. = +25 °C.

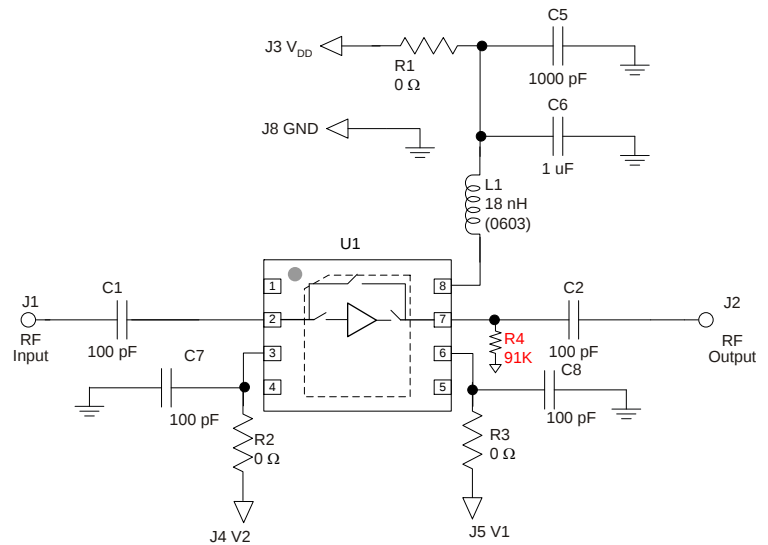
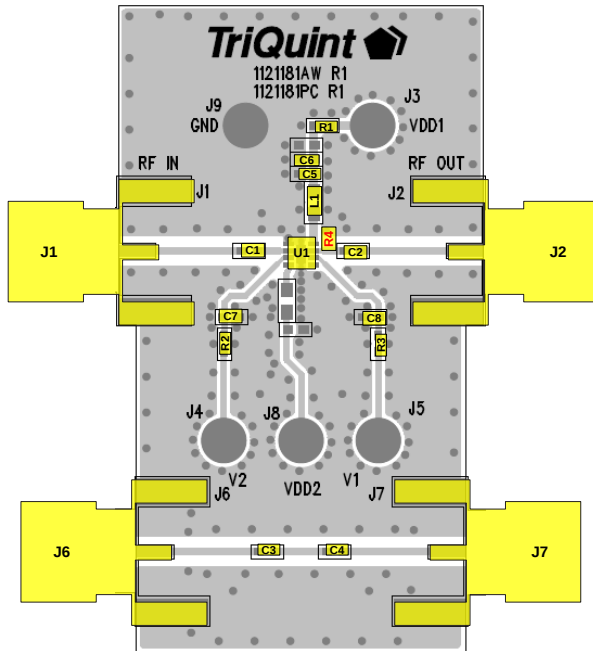
Parameter	Typical Value				Units
Frequency	700	1950	2600	3500	MHz
Isolation	23	17	15	15	dB

Performance Plots

Test conditions unless otherwise noted: $V_{DD} = +5\text{ V}$

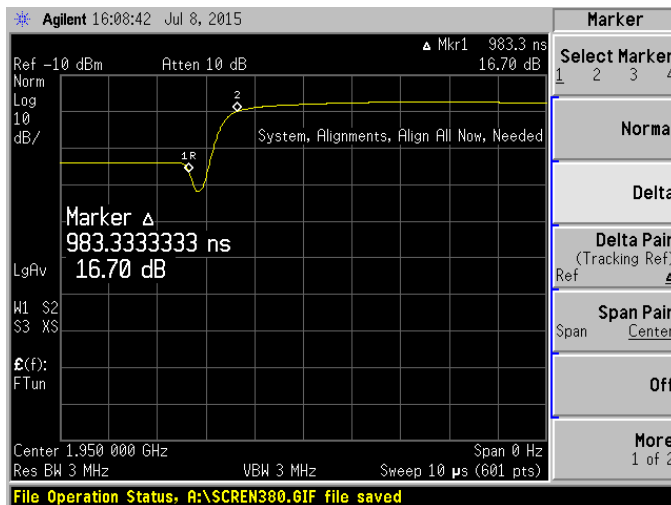


Switching Speed

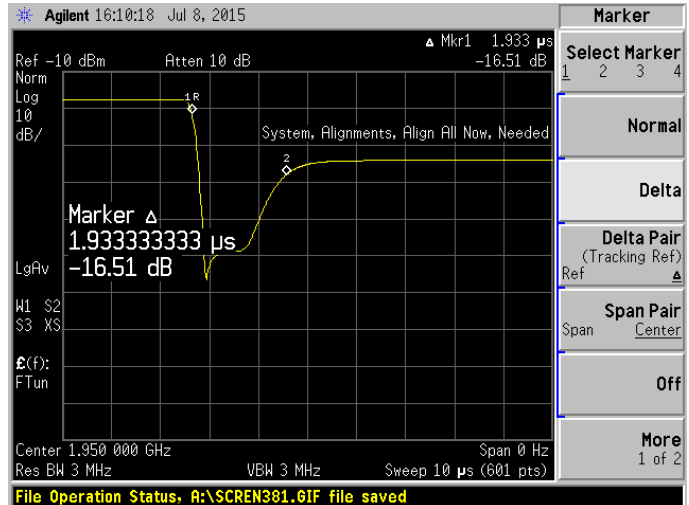


Transition	Value	Units
Bypass to LNA mode	983	ns
LNA to Bypass mode	1.9	μs

R4, valued 91K, is required to achieve the fast switching speeds listed above. The placement of R4 is shown on the Qorvo EVB above.

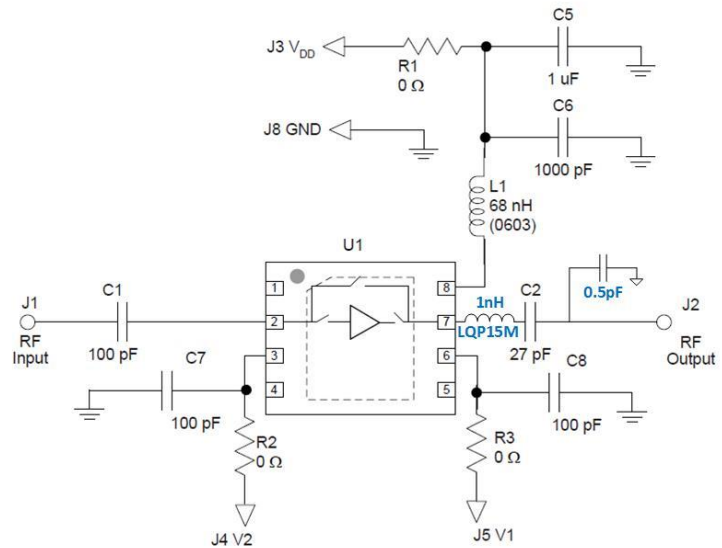
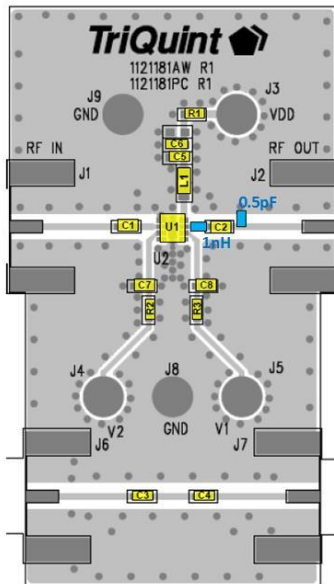


Bypass to LNA mode transition

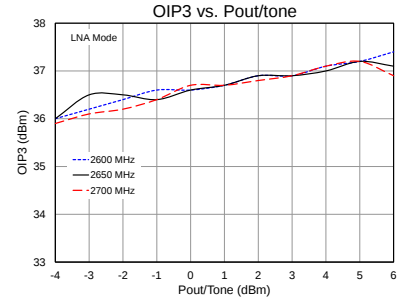
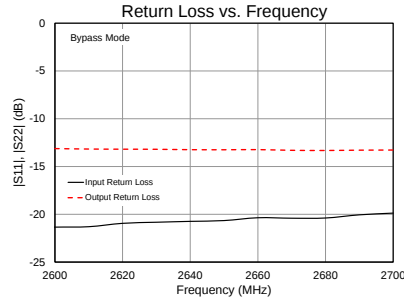
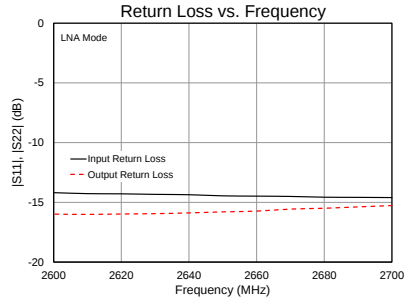


LNA to Bypass mode transition

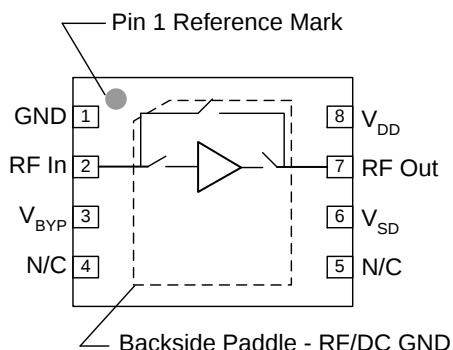
TQL9063 B7 Output RL Tune



See Evaluation Board PCB Information section for PCB material and stack-up.



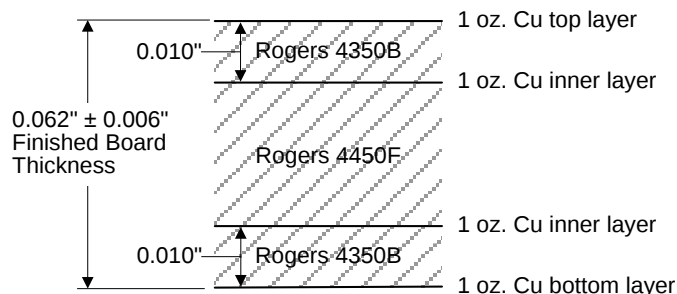
Pin Configuration and Description



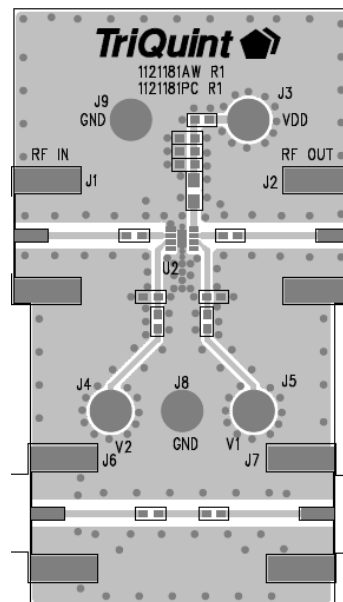
Pin No.	Label	Description
1	GND	RF/DC Ground pin.
2	RFin	RF input pin. DC block required.
3	V _{BYP}	Control pin for bypass mode. The LNA is automatically turned off when the bypass mode is activated. Refer to truth table.
4, 5	N/C	No internal connection. Provide grounded PCB land pads for mounting integrity.
6	V _{SD}	Control pin to disable the LNA. Refer to truth table.
7	RFout	RF output pin. DC block required.
8	V _{DD}	Supply voltage pin.
Backside Paddle	RF/DC GND	RF/DC Ground. Follow recommended via pattern and ensure good solder attach for best thermal and electrical performance.

Evaluation Board PCB Information

Qorvo PCB 1121181 Material and Stack-up



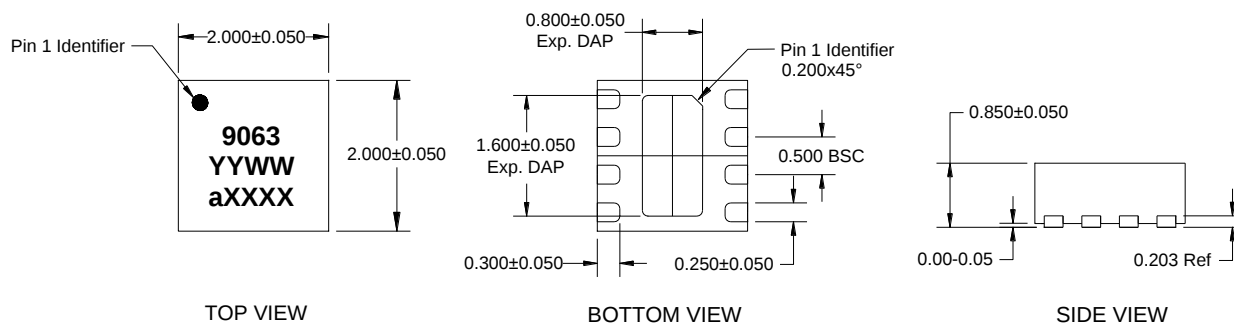
50 ohm line dimensions: width = .020", spacing = .032"



Mechanical Information

Package Marking and Dimensions

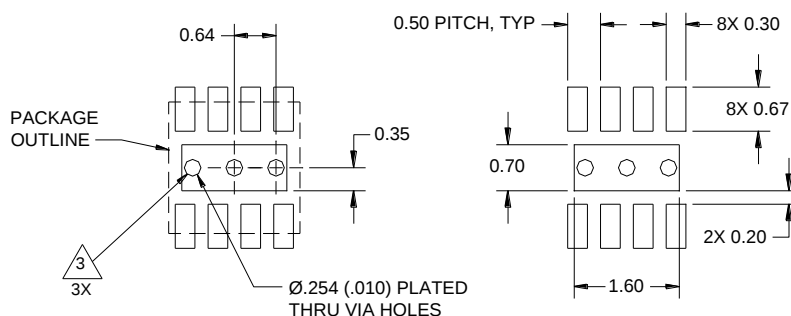
Marking: Part number – 9063
Year/Week – YYWW
Lot Code – aXXXX



NOTES:

1. All dimensions are in millimeters. Angles are in degrees.
2. Except where noted, this part outline conforms to JEDEC standard MO-229.
3. Dimension and tolerance formats conform to ASME Y14.4M-1994.
4. The terminal #1 identifier and terminal numbering conform to JESD 95-1 SPP-012.

PCB Mounting Pattern



NOTES:

1. All dimensions are in millimeters. Angles are in degrees.
2. Use 1 oz. copper minimum for top and bottom layer metal.
3. Vias are required under the backside paddle of this device for proper RF/DC grounding and thermal dissipation. We recommend a 0.35 mm ($\#80/.0135$ ") diameter bit for drilling via holes and a final plated thru diameter of 0.25 mm (0.10 ").
4. Ensure good package backside paddle solder attach for reliable operation and best electrical performance.

Product Compliance Information

ESD Sensitivity



Caution! ESD-Sensitive Device

ESD Rating: Class 1B
Value: 500V to < 1000V
Test: Human Body Model (HBM)
Standard: JEDEC Standard JS-001-2012

ESD Rating: Class C3
Value: > 1000V
Test: Charged Device Model (CDM)
Standard: JEDEC Standard JESD22-C101F

MSL Rating

MSL Rating: Level 1
Test: 260°C convection reflow
Standard: JEDEC Standard IPC/JEDEC J-STD-020

Solderability

Compatible with both lead-free (260°C max. reflow temperature) and tin/lead (245°C max. reflow temperature) soldering processes.

Package contact plating: NiPdAu

RoHS Compliance

This part is compliant with EU 2002/95/EC RoHS directive (Restrictions on the Use of Certain Hazardous Substances in Electrical and Electronic Equipment).

This product also has the following attributes:

- Lead Free
- Halogen Free (Chlorine, Bromine)
- Antimony Free
- TBBP-A (C₁₅H₁₂Br₄O₂) Free
- PFOS Free
- SVHC Free

Contact Information

For the latest specifications, additional product information, worldwide sales and distribution locations:

Web: www.triquint.com Tel: 877-800-8584
Email: customer.support@qorvo.com

For information about the merger of RFMD and TriQuint as Qorvo:

Web: www.qorvo.com

For technical questions and application information:

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